

1. A circuit material for the formation of circuits or multi-layer circuits, the circuit material comprising:
 - a first conductive layer; and
 - a dielectric layer disposed on the first conductive layer, wherein the dielectric layer comprises a crosslinkable liquid crystalline polymer comprising phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups.
2. The circuit material of claim 1, wherein the conductive layer is copper.
3. The circuit material of claim 1, wherein the dielectric layer is substantially nonflowable when fully crosslinked.
4. The circuit material of claim 1, wherein the dielectric layer further comprises a particulate filler, a fibrous web, or a combination comprising at least one of the foregoing.
5. The circuit material of claim 1, wherein dielectric layer is flowable when partially crosslinked.
6. The circuit material of claim 1, further comprising a second conductive layer disposed on the dielectric layer on a side opposite the first conductive layer.

7. The circuit material of claim 6, wherein the dielectric layer further comprises a particulate filler, a fibrous web, or a combination comprising at least one of the foregoing.

8. The circuit material of claim 1, wherein the crosslinkable liquid crystalline polymer comprises phenyl maleimide groups.

9. The circuit material of claim 1, having a dielectric constant of less than about 3.8, a dissipation factor of less than or equal to about 0.007 when measured from 1 to 10 GHz, and a UL-94 rating of V-1 or better, when the liquid crystalline polymer composition is fully crosslinked.

10. A circuit laminate for the formation of circuits or multi-layer circuits, the circuit laminate comprising:

a first conductive layer; and

a dielectric substrate disposed on the first conductive layer, wherein the dielectric substrate comprises a B-staged or thermoset liquid crystalline polymer having crosslinked groups derived from phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups.

11. The circuit laminate of claim 10, wherein the conductive layer is copper.

12. The circuit laminate of claim 10, wherein the dielectric substrate further comprises a particulate filler, a fibrous web, or a combination comprising at least one of the foregoing.

13. The circuit laminate of claim 10, having a dielectric constant of less than about 3.8, a dissipation factor of less than or equal to about 0.007 when measured at 1 to 10 GHz, and a UL-94 rating of V-1 or better when fully crosslinked.

14. A method of forming a circuit material, comprising
contacting a crosslinkable liquid crystalline polymer composition with a conductive layer, wherein the crosslinkable liquid crystalline polymer composition comprises a crosslinkable liquid crystalline polymer comprising phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups; and

crosslinking the crosslinkable liquid crystalline polymer to form a B-staged or thermoset liquid crystalline polymer dielectric material.

15. A circuit comprising:
a dielectric substrate comprising a thermoset liquid crystalline polymer having crosslinked phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups; and
a conductive circuit layer disposed on the dielectric substrate.

16. The circuit of claim 15, wherein the conductive layer is copper.

17. The circuit of claim 15, wherein the dielectric substrate further comprises a particulate filler, a fibrous web, or a combination comprising at least one of the foregoing.

18. The circuit of claim 15, having a dielectric constant of less than about 3.8, a dissipation factor of less than or equal to about 0.007 when measured from 1 to 10 GHz, and a UL-94 rating of V-1 or better.

19. A multi-layer circuit comprising:

a resin coated conductive layer comprising a first conductive layer disposed on a flowable dielectric material; and

a dielad circuit, comprising a dielectric substrate disposed between a circuit layer and a second conductive layer, wherein the flowable dielectric material is disposed on a side of the circuit layer opposite the dielectric substrate, and further wherein

the flowable dielectric material, the dielectric substrate, or both, comprises a thermoset liquid crystalline polymer having crosslinked phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups.

20. The multi-layer circuit of claim 1, wherein the first conductive layer, second conductive layer, and circuit layer are copper.

21. The multi-layer circuit of claim 19, having a dielectric constant of less than about 3.8, a dissipation factor of less than or equal to about 0.007, and a UL-94 rating of V-1 or better.

22. The multilayer circuit of claim 19, wherein the dielectric substrate further comprises a particulate filler, a fibrous web, or a combination comprising at least one of the foregoing.

23. A multi-layer circuit comprising:
a first dielectric circuit comprising a first dielectric substrate disposed between a first circuit layer and a second circuit layer;
a second dielectric circuit comprising a second dielectric substrate disposed between a third circuit layer and a fourth circuit layer; and
a bond ply disposed between the second circuit layer on a side opposite the first dielectric substrate layer, and the third circuit layer on a side opposite the second dielectric layer, wherein at least one of the first dielectric substrate, the second dielectric substrate, or the bond ply comprises a B-staged or thermoset liquid crystalline polymer having crosslinked phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups.

24. The multilayer circuit of claim 23, having a dielectric constant of less than about 3.8, a dissipation factor of less than or equal to about 0.007, and a UL-94 rating of V-1 or better.

25. The multilayer circuit of claim 23, wherein at least one of the first dielectric substrate, the second dielectric substrate, or the bond ply further comprises a particulate filler, a fibrous web, or a combination comprising at least one of the foregoing.

26. The multilayer circuit of claim 23, further comprising a cover film disposed on the first circuit layer on a side opposite the first dielectric layer, wherein the cover film comprises a thermoset liquid crystalline polymer formed by the crosslinking of phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups.

27. A B-staged circuit material for the formation of circuits or multi-layer circuits, the circuit material comprising:

a first conductive layer; and

a dielectric layer disposed on the first conductive layer, wherein the dielectric layer comprises a liquid crystalline polymer comprising phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups, wherein the groups have been partially crosslinked.

28. The B-staged circuit material of claim 27, wherein the conductive layer is copper.

29. A circuit material for the formation of circuits or multi-layer circuits, the circuit material comprising:

- a first conductive layer; and
- a dielectric layer disposed on the first conductive layer, wherein the dielectric layer comprises a liquid crystalline polymer comprising phenyl maleimide groups, nadimide groups, phenylacetylene groups, or a combination comprising at least one of the foregoing groups, and further wherein said groups crosslink at a temperature is at least about 20°C greater than the melt temperature of the liquid crystalline polymer.